

JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD

SOP14 Plastic-Encapsulate Operational Amplifiers

LM324 Low Power Quad Operational Amplifier

DESCRIPTION

The LM324 consists of four independent, high gain and internally frequency compensated operational amplifiers, it is specifically designed to operate from a single power supply. Operation from split power sup-ply is also possible and the low power supply current drain is independent of the magnitude of the power supply voltages.

Features

• Internally Frequency Compensated for Unity Gain

• Large Voltage Gain: 100dB (Typical)

• Low Input Bias Current: 45nA (Typical)

Low Input Offset Voltage: 2mV (Typical)

• Low Supply Current: 0.5mA (Typical)

Wide Power Supply Voltage Range:

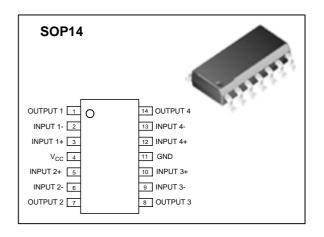
Single Supply: 3V to 30V

Dual Supplies: \pm 1.5V to \pm 15V

 Input Common Mode Voltage Range Includes Ground

Large Output Voltage Swing: 0V to V_{CC}-1.5V

Power Drain Suitable for Battery Operation



Applications

- · Battery Charger
- · Cordless Telephone
- Switching Power Supply

Functional Block Diagram

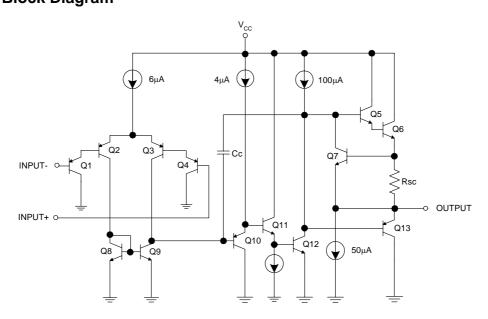


Figure 1. Functional Block Diagram of LM324

LM324 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Value	Unit
Power Supply Voltage	V _{CC}	32	V
Differential Input Voltage	V _{ID}	32	V
Input Voltage	V _{IC}	-0.3 to 32	V
Input Current (V _{IN} <-0.3V) (Note 2)	I _{IN}	50	mA
Output Short Circuit to Ground (One Amplifier) (Note 3) $V_{CC} \leq 15V \text{ and } T_A = 25^{o}C$		Continuous	
Power Dissipation $(T_A = 25^{\circ}C)$	P_{D}	400	mW
Junction Temperature	T_{J}	-25 to 125	°C
Storage Temperature Range	T _{STG}	-55 to 125	°C
Lead Temperature (Soldering, 10 Seconds)	T _{LEAD}	260	°C

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device under these conditions is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Note 2: This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the op amps to go to the V_{CC} voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than -0.3V (at 25° C)

Note 3: Short circuits from the output to V_{CC} can cause excessive heating and eventual destruction. When considering short circuits to ground, the maximum output current is approximately 40mA independent of the magnitude of V_{CC} . At values of supply voltage in excess of +15V, continuous short circuits can exceed the power dissipation ratings and cause eventual destruction. Destructive dissipation can result from simultaneous shorts on all amplifiers.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V _{CC}	3	30	V
Ambient Operating Temperature Range	T_A	0	70	°C

LM324 ELECTRICAL CHARACTERISTICS

 V_{CC} =5V, GND=0, T_A =25°C unless otherwise specified.

Parameter		Symbol	Test Conditions		Min	Тур	Max	Unit
Input Offset Voltag	ge	V _{IO}	$V_O=1.4V$, $R_S=0\Omega$, $V_{CC}=5V$ to $30V$			2	5	mV
Input Bias Current (Note 4)		I _{BIAS}	I_{IN} + or I_{IN} -, V_{CM} =0 V			45	250	nA
Input Offset Curren	nt	I _{IO}	I_{IN} +- I_{IN} -, V_{CM} =0 V			5	50	nA
Input Common Mo Voltage Range (No		V _{IR}	V _{CC} =30V	V _{CC} =30V			V _{CC} -1.5	V
Supply Current		I_{CC}	11 OD A	$V_{\text{CC}=30V}$		1.5	3	mA
				V _{CC=5} V		0.6	2	
Large Signal Volta	Signal Voltage Gain G_V $V_{CC}=15V, R_L \ge 2k\Omega, V_O=1V \text{ to } 11V$			88	100		dB	
Common Mode Re Ratio	ejection	CMRR	V _{CM} =0V to (V _{CC} -1.5)V		65	85		dB
Power Supply Reje Ration	ection	PSRR	V _{CC} =5V to 30V		65	100		dB
Channel Separation (Note 6)		CS	f=1kHz to 20kHz			-120		dB
	Source	I _{SOURCE}	V _{IN} +=1V, V _{IN} -=0V, V _{CC} =15V	20	35		mA	
Output Current	Sink	I _{SINK}	V _{IN} +=0V, V _{IN} -=1V, V _{CC} =15V	, V _O =2V	10	13		mA
			V_{IN} +=0V, V_{IN} -=1V, V_{CC} =15V	, V _O =0.2V	12	50		μA
Output Short C Ground	Circuit to	I_{SC}	V _{CC} =15V			40	60	mA
	V _{OH}	V_{CC} =30V, R_L =2k Ω		26			V	
Output Voltage Swing		V_{CC} =30V, R_L =10k Ω		27	28			
		V _{OL}	V_{CC} =5V, R_L =10k Ω			5	20	mV
Thermal Resistanc (Junction to Case)	e	$\theta_{ m JC}$				98.84		°C/W
Slew Rate		SR	G = +1, 2V Output Step			0.5		V/µs

Note 4: The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the input lines.

Note 5: The input common-mode voltage of either input signal voltage should not be allowed to go negatively by more than 0.3V (at $25^{\circ}C$). The upper end of the common-mode voltage range is V_{CC} -1.5V (at $25^{\circ}C$), but either or both inputs can go to +32V without damages, independent of the magnitude of the V_{CC} .

Note 6: Due to proximity of external components, insure that coupling is not originating via stray capacitors between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.

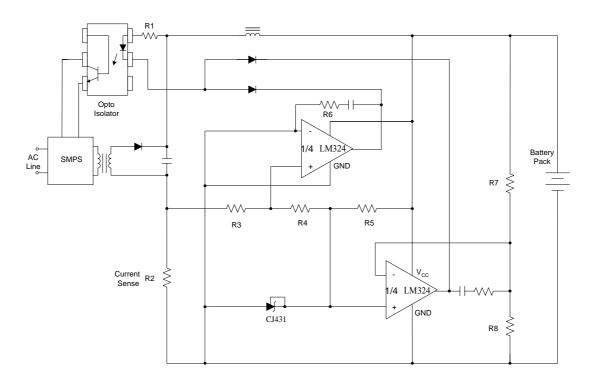


Figure 2. Battery Charger

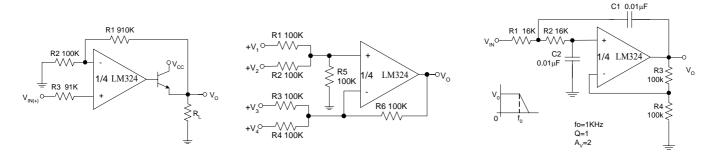


Figure 3. Power Amplifier

Figure 4. DC Summing Amplifier

Figure 5. DC Coupled Low-Pass Active Filter

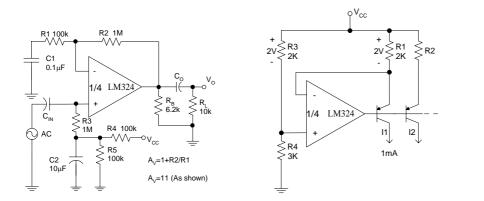


Figure 6. AC Coupled Non-Inverting Amplifier

Figure 7. Fixed Current Sources

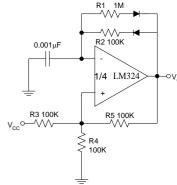
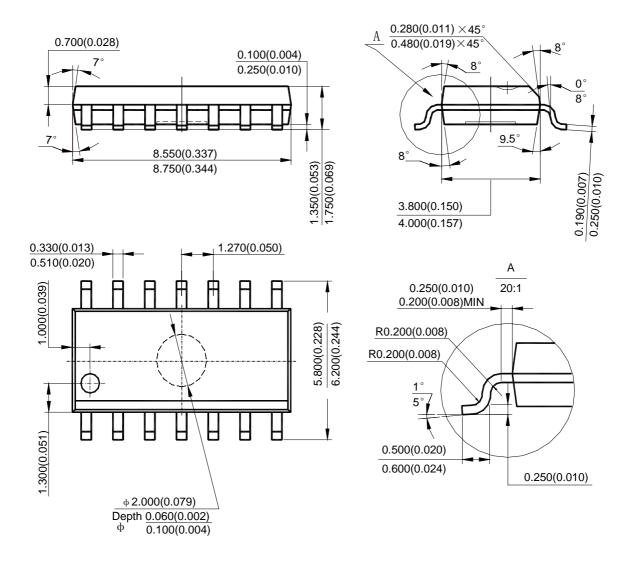


Figure 8. Pulse Generator

Unit: mm(inch)



Note: Eject hole, oriented hole and mold mark is optional.

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